

MOSFETs Silicon N-Channel MOS

SSM3K62TU

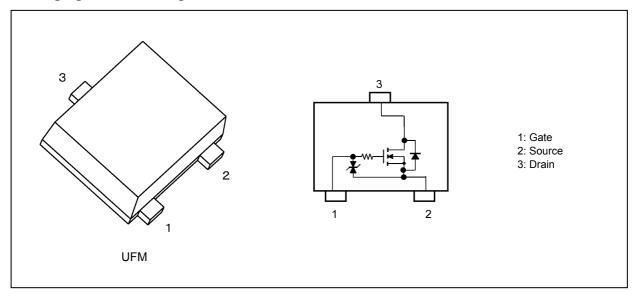
1. Applications

- · Power Management Switches
- · DC-DC Converters

2. Features

- (1) 1.2-V drive
- (2) Low drain-source on-resistance
 - $: R_{DS(ON)} = 43 \text{ m}\Omega \text{ (typ.) } (@V_{GS} = 4.5 \text{ V})$
 - $R_{\rm DS(ON)} = 50 \ {\rm m}\Omega \ {\rm (typ.)} \ (@V_{\rm GS} = 2.5 \ {\rm V})$
 - $R_{\rm DS(ON)} = 60 \ {\rm m}\Omega \ ({\rm typ.}) \ (@V_{\rm GS} = 1.8 \ {\rm V})$
 - $R_{\mathrm{DS(ON)}} = 70~\mathrm{m}\Omega$ (typ.) (@ $V_{\mathrm{GS}} = 1.5~\mathrm{V}$)
 - $R_{\mathrm{DS(ON)}} = 98 \ \mathrm{m}\Omega \ (\mathrm{typ.}) \ (@V_{\mathrm{GS}} = 1.2 \ \mathrm{V})$

3. Packaging and Pin Assignment





4. Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25 °C)

	Characteristics		Symbol	Rating	Unit
Drain-source voltage			V_{DSS}	20	V
Gate-source voltage			V_{GSS}	±8	
Drain current (DC)		(Note 1)	Ι _D	0.8	Α
Drain current (pulsed)		(Note 1), (Note 2)	I_{DP}	1.6	
Power dissipation		(Note 3)	P_D	500	mW
Power dissipation	t ≤ 10s	(Note 3)	P_{D}	1000	mW
Channel temperature			T _{ch}	150	°C
Storage temperature			T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Ensure that the channel temperature does not exceed 150°C.
- Note 2: Pulse width (PW) \leq 10 s, duty \leq 1%
- Note 3: Device mounted on an FR4 board. (PD for the entire IC) (FR4, 25.4 mm \times 25.4 mm \times 1.6 mm, Cu pad: 645 mm²)

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance, R_{th(ch-a)}, and the drain power dissipation, P_D, vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.



5. Electrical Characteristics

5.1. Static Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$	_	_	±10	μА
Drain cut-off current		I _{DSS}	V _{DS} = 10 V, V _{GS} = 0 V	_	_	1	
Drain-source breakdown voltage		V _{(BR)DSS}	I _D = 1 mA, V _{GS} = 0 V	20	_	_	V
Drain-source breakdown voltage	(Note 1)	V _{(BR)DSX}	I _D = 1 mA, V _{GS} = -5 V	15	_	_	
Gate threshold voltage	(Note 2)	V _{th}	V _{DS} = 3 V, I _D = 1 mA	0.4	0.6	1.0	
Drain-source on-resistance	(Note 3)	R _{DS(ON)}	I _D = 100 mA, V _{GS} = 1.2 V	_	98	432	mΩ
			I _D = 200 mA, V _{GS} = 1.5 V	_	70	139	
			I _D = 600 mA, V _{GS} = 1.8 V	_	60	89	
			I _D = 800 mA, V _{GS} = 2.5 V	_	50	68	
			I _D = 800 mA, V _{GS} = 4.5 V	_	43	57	
Forward transfer admittance	(Note 3)	Y _{fs}	V _{DS} = 3 V, I _D = 200 mA	_	3.0	1	S

Note 1: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

Note 2: Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (1 mA for this device). Then, for normal switching operation, $V_{GS(ON)}$ must be higher than V_{th} , and $V_{GS(OFF)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$.

Take this into consideration when using the device.

Note 3: Pulse measurement.

5.2. Dynamic Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$	_	177	_	pF
Reverse transfer capacitance	C _{rss}	f = 1 MHz	_	17	_	
Output capacitance	Coss		_	52	_	
Switching time (turn-on time)	t _{on}	V _{DD} = 10 V, I _D = 800 mA,	_	332	_	ns
Switching time (turn-off time)	t _{off}	V_{GS} = 0 to 4.5 V, R_{G} = 50 Ω	_	2653	_	

5.3. Switching Time Test Circuit

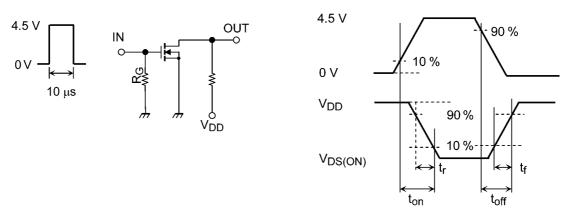


Fig. 5.3.1 Switching Time Test Circuit

Fig. 5.3.2 Input Waveform/Output Waveform

5.4. Gate Charge Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	V_{DD} = 10 V, I_{D} = 800 mA,	_	2.0		nC
Gate-source charge 1	Q _{gs1}	V _{GS} = 4.5 V	_	1.3	_	
Gate-drain charge	Q _{gd}		_	0.6		



5.5. Source-Drain Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	(Note 1)	V_{DSF}	$I_D = -800 \text{ mA}, V_{GS} = 0 \text{ V}$		-0.6	-1.2	V

Note 1: Pulse measurement.

6. Marking

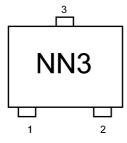


Fig. 6.1 Marking

7. Characteristics Curves (Note)

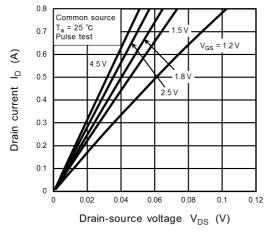


Fig. 7.1 I_D - V_{DS}

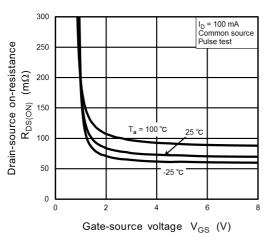


Fig. 7.3 R_{DS(ON)} - V_{GS}

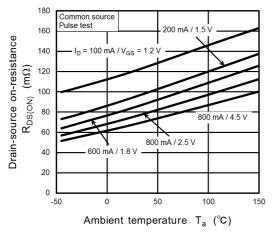


Fig. 7.5 R_{DS(ON)} - T_a

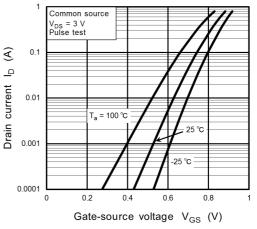


Fig. 7.2 I_D - V_{GS}

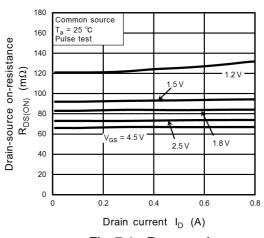


Fig. 7.4 R_{DS(ON)} - I_D

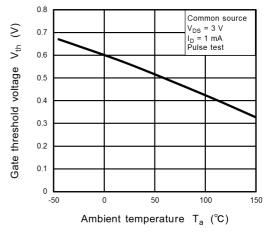
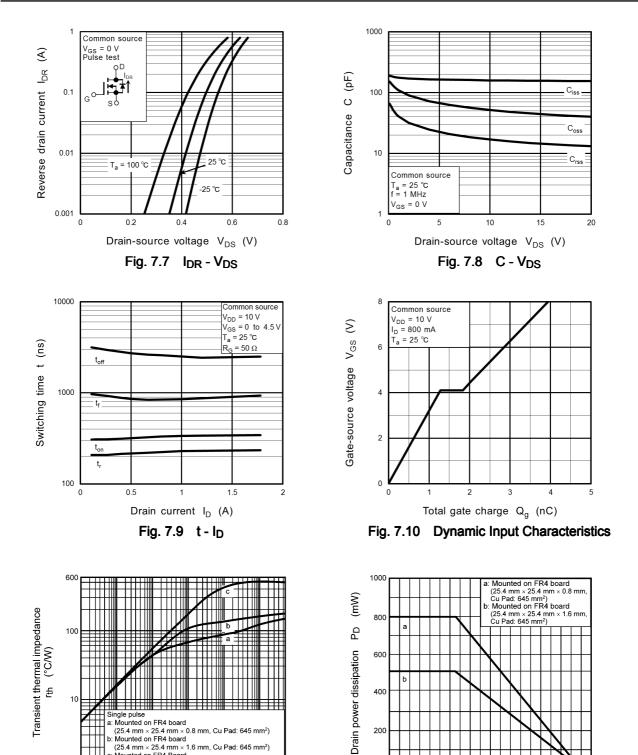


Fig. 7.6 V_{th} - T_a



The above characteristics curves are presented for reference only and not guaranteed by production test, Note: unless otherwise noted.

400

200

60 80

Ambient temperature Ta (°C)

Fig. 7.12 P_D - T_a

100 120

140 160

0.001

(25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 645 mm²) : Mounted on FR4 Board

Pulse width tw

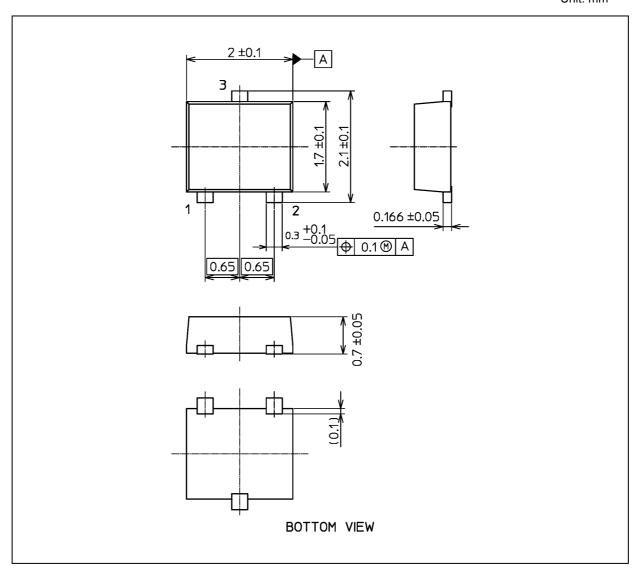
Fig. 7.11 rth - tw

100



Package Dimensions

Unit: mm



Weight: 6.6 mg (typ.)

	Package Name(s)	
Nickname: UFM		



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